## NSN 5961-01-371-2621

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-371-2621 **Inclosure Material:** Metal **Overall Length:** 1.030 inches **Overall Diameter:** 0.975 inches **Internal Configuration:** Junction contact **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 500.00 nanoamperes emitter current, dc peak **Special Features:** Junction pattern arrangement: pn **Specification Data:** 33030-1229567 manufacturers source control Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** Yes - demil/mli

**Fiig:** A110a0